

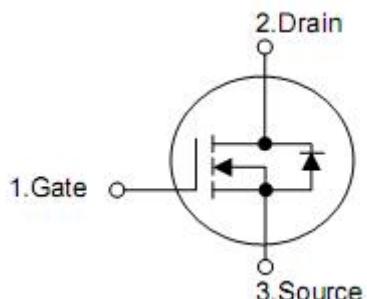
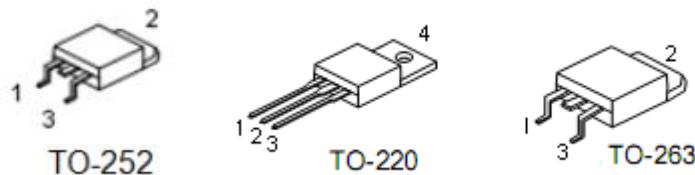
## 1. Features

- $R_{DS(on)}=2.2\text{m}\Omega$  (typ.) @  $V_{GS}=10\text{V}$
- Low On-Resistance
- Fast Switching
- 100% Avalanche Tested
- Repetitive Avalanche Allowed up to  $T_{jmax}$
- Lead-Free, RoHS Compliant

## 2. Features

KNX2803A designed by the trench processing techniques to achieve extremely low on-resistance. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Motor applications and a wide variety of other applications.

## 3. Pin configuration



Pin	Function
1	Gate
2	Drain
3	Source
4	Drain

## 4. Ordering Information

Part Number	Package	Brand
KNP2803A	TO-220	KIA
KNB2803A	TO-263	KIA
KND2803A	TO-252	KIA

## 5. Absolute maximum ratings

Parameter	Symbol	Ratings		Units
		TO-252	TO-263/220	
Drain-source voltage	V <sub>DSS</sub>	30		V
Gate-source voltage	V <sub>GSS</sub>	±20		V
Continuous drain current @ V <sub>GS</sub> =10V, T <sub>C</sub> =25 °C, (See Fig2)	I <sub>D</sub>	150		A
Pulsed drain current tested T <sub>C</sub> =25 °C (Silicon Limit)	I <sub>DM</sub>	600		A
Avalanche energy single pulse <sup>2</sup>	E <sub>AS</sub>	625		mJ
Maximum Power dissipation T <sub>C</sub> =25 °C	P <sub>D</sub>	50	160	W
Maximum junction temperature	T <sub>J</sub>	175		°C
Storage temperature range	T <sub>STG</sub>	-55~+175		°C
Diode continuous forward current T <sub>C</sub> =25 °C <sup>1</sup>	I <sub>S</sub>	150		A

## 6. Thermal characteristics

Parameter	Symbol	Rating		Unit
		TO-252	TO-263/220	
Thermal resistance, Junction-to-case	θ <sub>JC</sub>	3.0	0.93	°C/W

## 7. Electrical characteristics

( $T_c=25^\circ\text{C}$ ,unless otherwise notes)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	30	-	-	V
Drain-to-source leakage current	$I_{\text{DS}(\text{off})}$	$V_{\text{DS}}=24\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
		$T_c=125^\circ\text{C}$	-	-	100	$\mu\text{A}$
Gate-to-source leakage current	$I_{\text{GSS}}$	$V_{\text{GS}}=20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	100	nA
		$V_{\text{GS}}=-20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	-100	nA
<b>On characteristics</b>						
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	0.8	1.3	2.0	V
Static drain-source on-resistance <sup>1</sup>	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=40\text{A}$	-	2.2	3.0	$\text{m}\Omega$
Static drain-source on-resistance <sup>1</sup>	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=40\text{A}$	-	2.8	4.0	$\text{m}\Omega$
<b>Dynamic characteristics</b>						
Input capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=0\text{V}, f=1.0\text{MHz}$	-	4050	-	pF
Output capacitance	$C_{\text{oss}}$		-	680	-	
Reverse transfer capacitance	$C_{\text{rss}}$		-	355	-	
Total gate charge	$Q_g$	$V_{\text{DS}}=15\text{V}, I_{\text{D}}=20\text{A}, V_{\text{GS}}=4.5\text{V}$	-	110	-	nC
Gate-source charge	$Q_{\text{gs}}$		-	35	-	
Gate-drain (Miller)charge	$Q_{\text{gd}}$		-	14	-	
<b>Resistive switching characteristics</b>						
Turn-on delay time	$T_{\text{d}(\text{ON})}$	$V_{\text{DD}}=15\text{V}, I_{\text{D}}=10\text{A}, V_{\text{GS}}=4.5\text{V}, R_{\text{G}}=6.8\Omega$	-	19	-	nS
Rise time	$t_{\text{rise}}$		-	50	-	
Turn-off delay time	$T_{\text{d}(\text{OFF})}$		-	20	-	
Fall time	$t_{\text{fall}}$		-	26	-	
<b>Source-drain body diode characteristics</b>						
Diode forward voltage <sup>1</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{SD}}=20\text{A}$	-	-	1.3	V
Reverse recovery time	$t_{\text{rr}}$	$I_{\text{SD}}=30\text{A}, dI_{\text{F}}/dt=100\text{A}/\mu\text{s}, T_j=25^\circ\text{C}, V_{\text{GS}}=0\text{V}$	-	32	-	ns
Reverse recovery charge	$Q_{\text{rr}}$		-	33	-	nC

Note: 1. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

2. Limited by  $T_{\text{jmax}}$ , Starting  $T_j=25^\circ\text{C}, L=0.5\text{mH}, R_{\text{G}}=25\Omega, I_{\text{AS}}=50\text{A}, V_{\text{GS}}=10\text{V}$ ,

Part not recommended for use above this value.

3. Repetitive rating; pulse width limited by max, junction temperature.

## 8. Typical characteristics

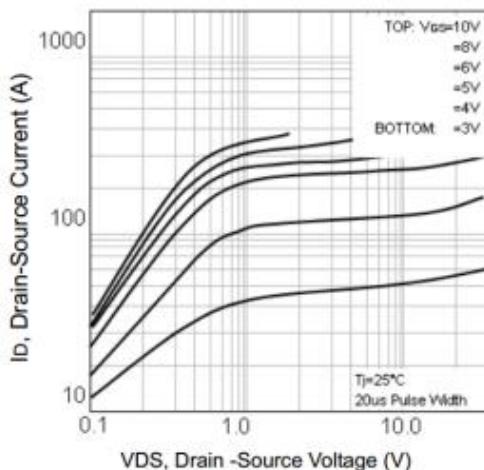


Fig1. Typical Output Characteristics

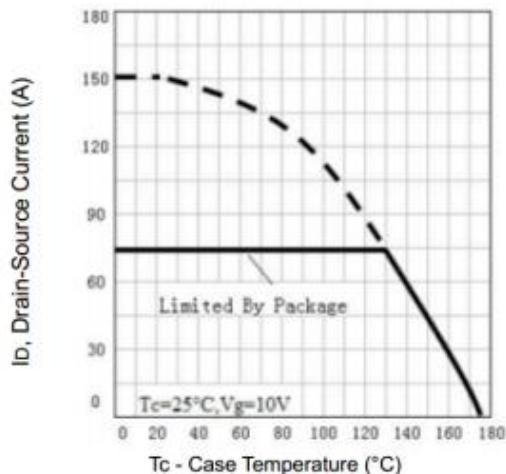


Fig2. Maximum Drain Current Vs. Case Temperature

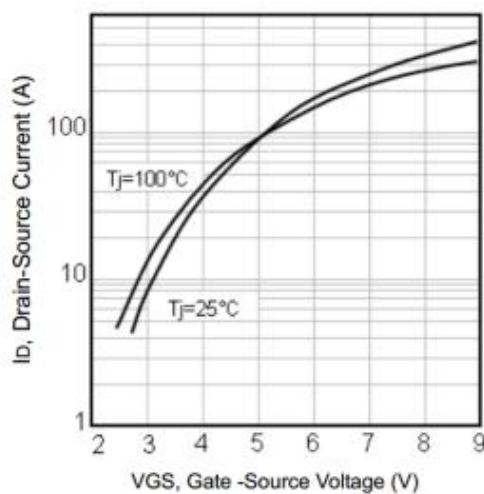


Fig3. Typical Transfer Characteristics

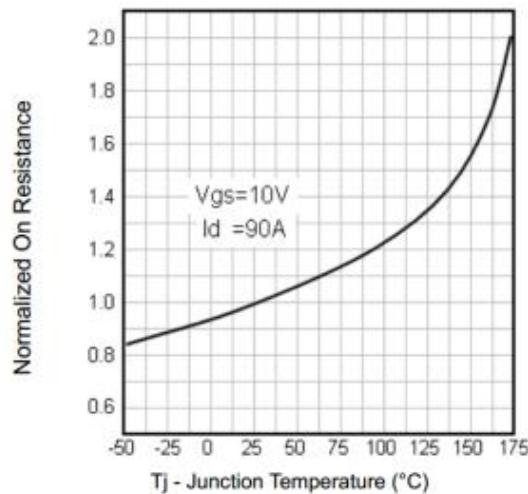


Fig4. Normalized On-Resistance Vs. Temperature

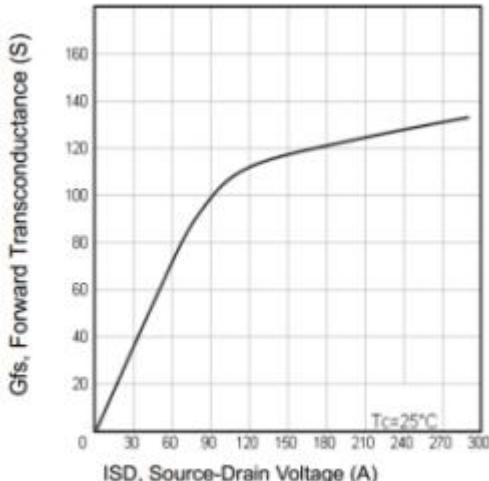


Fig5. Typical Forward Transconductance Vs. Drain Current

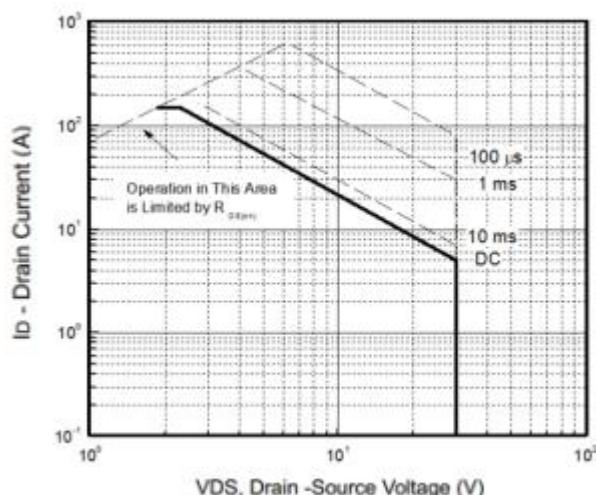


Fig6. Maximum Safe Operating Area

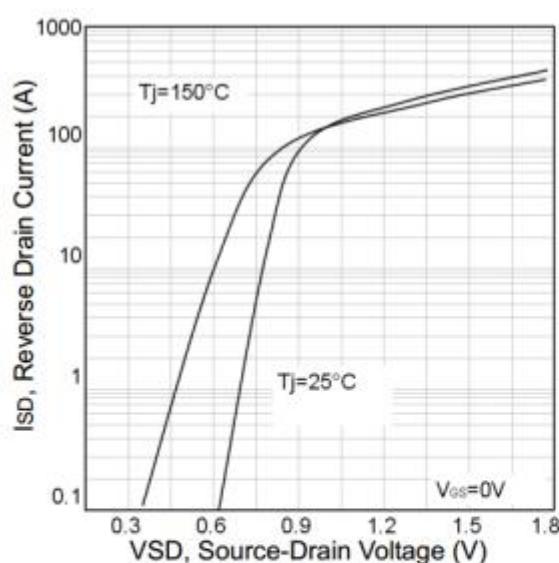


Fig7. Typical Source-Drain Diode Forward Voltage

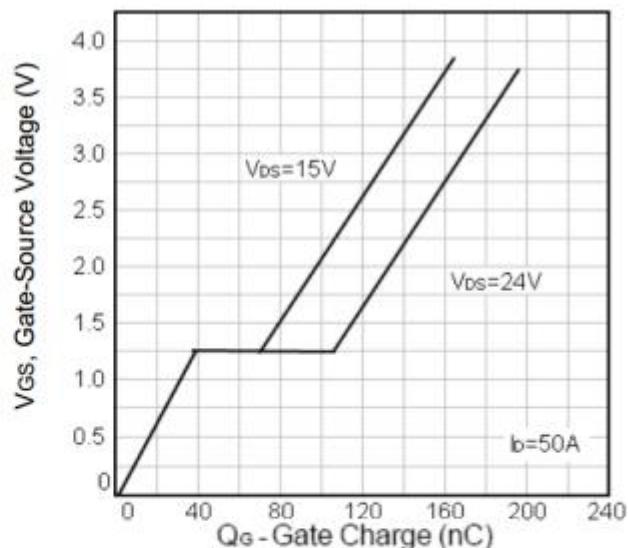


Fig8. Typical Gate Charge Vs.Gate-Source Voltage

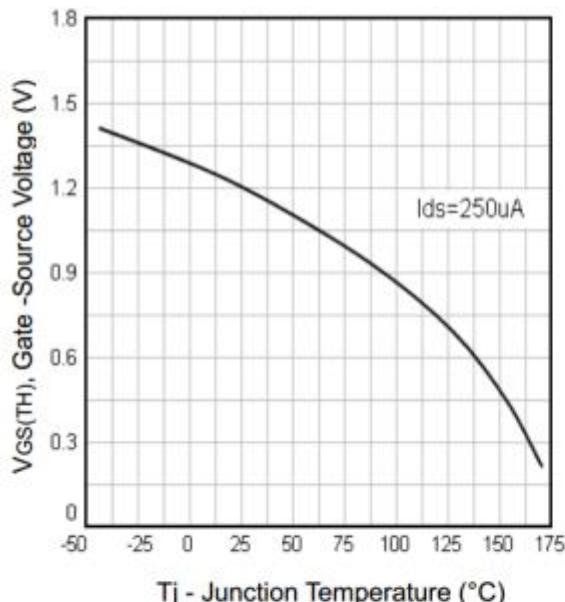


Fig9. Threshold Voltage Vs. Temperature

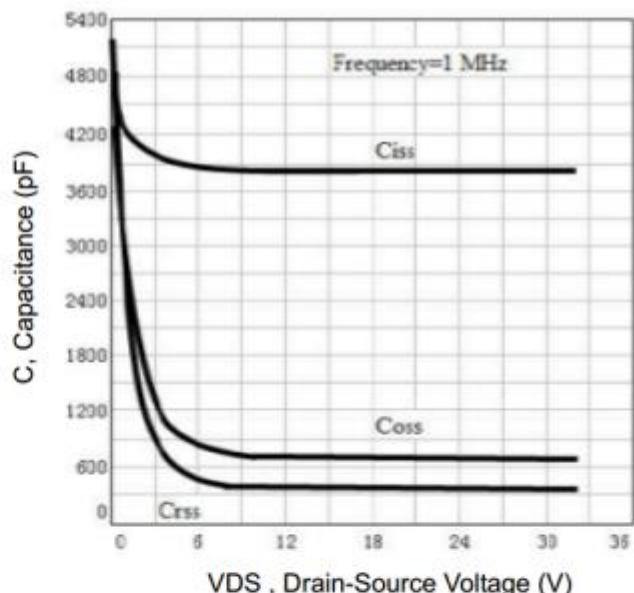


Fig10. Typical Capacitance Vs.Drain-Source Voltage

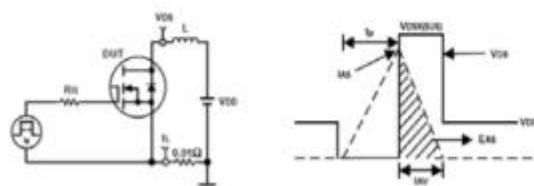


Fig11. Unclamped Inductive Test Circuit and waveforms

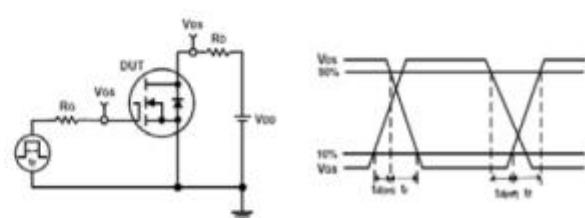


Fig12. Switching Time Test Circuit and waveforms

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